

NX8311UD

1 310 nm FOR LONG HAUL 2.5 Gb/s InGaAsP MQW-DFB LASER DIODE TOSA

DESCRIPTION

The NX8311UD is a 1 310 nm Multiple Quantum Well (MQW) structured Distributed Feed-Back (DFB) laser diode TOSA (transmitter optical subassembly) with InGaAs monitor PIN-PD in a receptacle type package designed for SFF/SFP transceiver with LC duplex receptacle.

FEATURES

Applications
 STM-16 (L-16.1), SONET OC-48 (LR)

· Internal optical isolator

• Optical output power P_f = 2.0 mW

• Low threshold current $l_{th} = 10 \text{ mA TYP.} @ T_{C} = 25^{\circ}\text{C}$

• Wide operating temperature range $Tc = -20 \text{ to } +85^{\circ}C$

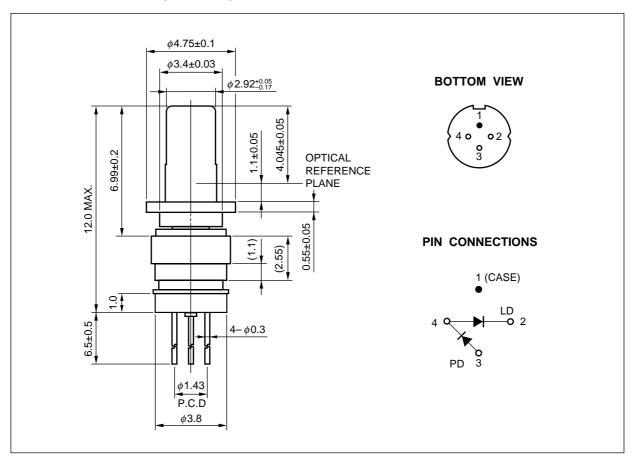
• InGaAs monitor PIN-PD

★ • Small package \$\phi 3.8 \text{ mm TOSA (Total length 12.0 mm MAX.)}



The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

★ PACKAGE DIMENSIONS (UNIT: mm)



ORDERING INFORMATION (Solder Contains Lead)

Part Number	Package	Pin Connections
NX8311UD	ϕ 3.8 mm TOSA	4 0 LD 2 PD 3

ORDERING INFORMATION (Pb-Free)

Part Number	Package	Pin Connections
NX8311UD-AZ*	ϕ 3.8 mm TOSA	4 0 LD 2 PD 3

*NOTE:

Please refer to the last page of this data sheet, "Compliance with EU Directives" for PB-Free RoHS Compliance Information.

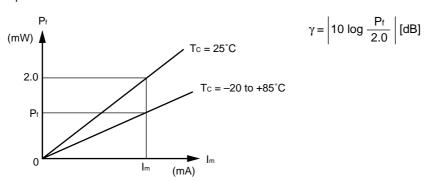
ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Ratings	Unit
Optical Output Power from Fiber	Pf	5.0	mW
Forward Current of LD	lF	150	mA
Reverse Voltage of LD	VR	2.0	V
Forward Current of PD	lF	2.0	mA
Reverse Voltage of PD	VR	15	V
Operating Case Temperature	Tc	-20 to +85	°C
Storage Temperature	Tstg	-40 to +85	°C
Lead Soldering Temperature	T _{sld}	350 (3 sec.)	°C

ELECTRO-OPTICAL CHARACTERISTICS ($Tc = -20 \text{ to } +85^{\circ}\text{C}$, unless otherwise specified)

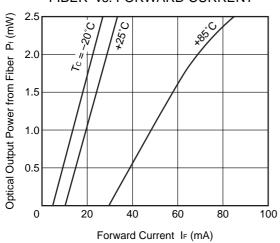
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Operating Voltage	Vop	CW, P _f = 2.0 mW		1.2	1.6	V
Threshold Current	Ith	CW,	2		50	mA
		CW, Tc = 25°C	4	10	20	
Optical Output Power from Fiber	Pf	cw		2.0		mW
Modulation Current	Imod	CW, P _f = 2.0 mW	7		50	mA
		CW, P _f = 2.0 mW, T _C = 25°C	9	20	30	
Differential Efficiency	$\eta_{ ext{d}}$	CW, P _f = 2.0 mW	0.04		0.29	W/A
		CW, P _f = 2.0 mW, T _C = 25°C	0.07	0.10	0.20	
Peak Emission Wavelength	λρ	CW, P _f = 2.0 mW, RMS (-20 dB)	1 280		1 335	nm
Side Mode Suppression Ratio	SMSR	CW, P _f = 2.0 mW	30			dB
Rise Time	tr	lb = lth, 10-90%			200	ps
Fall Time	t f	lb = lth, 90-10%			200	ps
Monitor Current	Im	CW, V _R = 1.5 V, P _f = 1.0 mW	100		2 000	μА
Monitor Dark Current	lo	VR = 1.5 V			500	nA
		VR = 1.5 V, Tc = 25°C			50	
Tracking Error ^{*1}	γ	CW, Im = const. (@ Pf = 2.0 mW)	-1.0		1.0	dB
Connector Repeatability	_	With master pigtail	-1.0		1.0	dB
Optical Isolation	Is	CW, P _f = 2.0 mW	20			dB

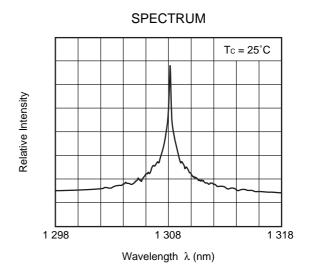
*1 Tracking Error: γ



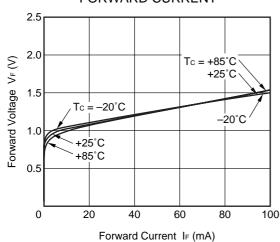
★ TYPICAL CHARACTERISTICS (Tc = 25°C, unless otherwise specified)





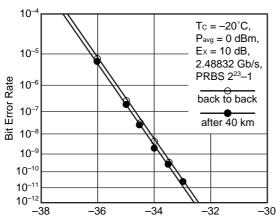


FORWARD VOLTAGE vs. FORWARD CURRENT



Remark The graphs indicate nominal characteristics.

ERROR RATE CHARACTERISTICS



Average Received Power \overline{P} (dBm)

EYE DIAGRAM

Relative Intensity (20 mV/div.)

Wask
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Failed steps 0

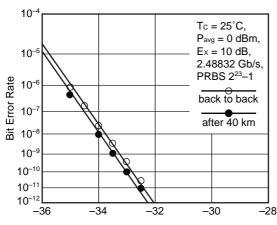
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1

2

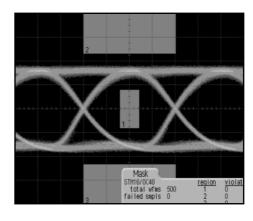
Back to Back (100 ps/div.)

ERROR RATE CHARACTERISTICS



Average Received Power P (dBm)

EYE DIAGRAM

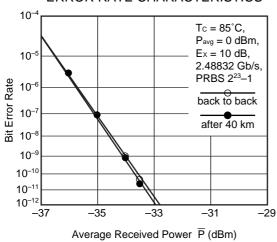


Relative Intensity (20 mV/div.)

Relative Intensity (20 mV/div.)

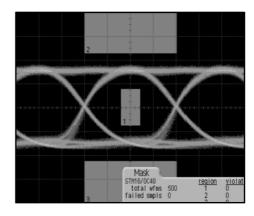
Back to Back (100 ps/div.)

ERROR RATE CHARACTERISTICS



Remark The graphs indicate nominal characteristics.

EYE DIAGRAM



Back to Back (100 ps/div.)

LD $\,\phi$ 3.8 mm FP-TOSA PACKAGES FAMILY FOR OPTICAL FIBER COMMUNICATIONS

			Electi	ro-Optical	Characte	ristics		
Part Number	Absolute Max	imum Ratings	@Tc = 25°C		@Tc		Application	Dookogo
Fait Number	Tc (°C)	T _{stg} (°C)	I _{th} (mA)	P _f (mW)		m)	Application	Package
			TYP.	TYP.	MIN.	MAX.		
NX7312UA-AZ*	-40 to +85	-40 to +85	8	0.2	1 274	1 356	156 Mb/s: STM-1 (S-1.1)	φ 3.8 mm TOSA
							622 Mb/s: STM-4 (S-4.1)	
NX7313UA-AZ*	-40 to +85	-40 to +85	8	0.6	1 270	1 355	1.25 Gb/s: GbE	φ 3.8 mm TOSA
NX7314UA-AZ*	-40 to +85	-40 to +85	8	1.0	1 263	1 360	156 Mb/s: STM-1 (L-1.1)	φ 3.8 mm TOSA
NX7315UA-AZ*	-40 to +85	-40 to +85	8	0.6	1 266	1 360	2.5 Gb/s: STM-16 (I-16)	φ 3.8 mm TOSA

*NOTE:

Please refer to the last page of this data sheet, "Compliance with EU Directives" for PB-Free RoHS Compliance Information.

LD ϕ 3.8 mm DFB-TOSA PACKAGES FAMILY FOR OPTICAL FIBER COMMUNICATIONS

			Electi	o-Optical	Characte	ristics		Package	
Part Number	Absolute Max	imum Ratings	@Tc = 25°C		@Tc		Application		
Fait Number	Tc (°C)	T _{stg} (°C)	I _{th} (mA)	P _f (mW)		m)	Application	Package	
			TYP.	TYP.	MIN.	MAX.			
NX8310UA-AZ*	-40 to +85	-40 to +85	10	2.0	1 280	1 335	622 Mb/s: STM-4 (L-4.1)	ϕ 3.8 mm TOSA	
NX8311UD-AZ*	-20 to +85	-40 to +85	10	2.0	1 280	1 335	2.5 Gb/s: STM-16 (L-16.1)	ϕ 3.8 mm TOSA	
NX8312UA-AZ*	-20 to +85	-40 to +85	10	1.0	1 280	1 335	2.5 Gb/s: STM-16 (S-16.1)	ϕ 3.8 mm TOSA	
NX8312UD-AZ*	-20 to +85	-40 to +85	10	1.0	1 280	1 335	2.5 Gb/s: STM-16 (S-16.1)	φ 3.8 mm TOSA	

*NOTE:

Please refer to the last page of this data sheet, "Compliance with EU Directives" for PB-Free RoHS Compliance Information.

REFERENCE

Document Name	Document No.
OPTICAL SEMICONDUCTOR DEVICES FOR FIBEROPTIC COMMUNICATIONS SELECTION GUIDE	PX10161E
Opto-Electronics Devices Pamphlet	PX10160E



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Subject: Compliance with EU Directives

CEL certifies, to its knowledge, that semiconductor and laser products detailed below are compliant with the requirements of European Union (EU) Directive 2002/95/EC Restriction on Use of Hazardous Substances in electrical and electronic equipment (RoHS) and the requirements of EU Directive 2003/11/EC Restriction on Penta and Octa BDE.

CEL Pb-free products have the same base part number with a suffix added. The suffix –A indicates that the device is Pb-free. The –AZ suffix is used to designate devices containing Pb which are exempted from the requirement of RoHS directive (*). In all cases the devices have Pb-free terminals. All devices with these suffixes meet the requirements of the RoHS directive.

This status is based on CEL's understanding of the EU Directives and knowledge of the materials that go into its products as of the date of disclosure of this information.

Restricted Substance per RoHS	Concentration Limit per RoHS (values are not yet fixed)	Concentration in CEL	on contained devices	
Lead (Pb)	< 1000 PPM	-A Not Detected	-AZ (*)	
Mercury	< 1000 PPM	Not Detected		
Cadmium	< 100 PPM	Not Detected		
Hexavalent Chromium	< 1000 PPM	Not Detected		
PBB	< 1000 PPM	Not Detected		
PBDE	< 1000 PPM	Not Detected		

If you should have any additional questions regarding our devices and compliance to environmental standards, please do not hesitate to contact your local representative.

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